

SCCS033 - May 1994 - Revised March 2000

8-/9-/10-Bit Bus Interface Registers

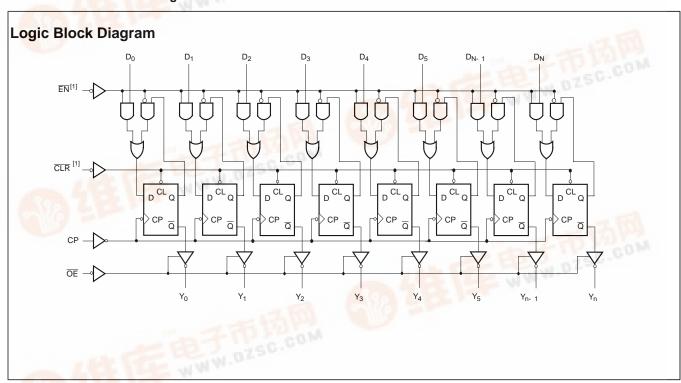
Features

- Function, pinout, and drive compatible with FCT, F, and Am29821/23/25 logic
- FCT-C speed at 6.0 ns max. FCT-B speed at 7.5 ns max.
- Reduced V_{OH} (typically = 3.3V) versions of equivalent FCT functions
- Edge-rate control circuitry for significantly improved noise characteristics
- Power-off disable feature
- Matched rise and fall times
- Fully compatible with TTL input and output logic levels
- ESD > 2000V
- Sink current 64 mA Source current 32 mA
- High-speed parallel registers with positive edge-triggered D-type flip-flops
- Buffered common clock enable (EN) and asynchronous clear input (CLR)
- Extended commercial range of -40°C to +85°C

Functional Description

These bus interface registers are designed to eliminate the extra packages required to buffer existing registers and provide extra data width for wider address/data paths or buses carrying parity. The FCT821T is a buffered, 10-bit wide version of the popular FCT374 function. The FCT823T is a 9-bit wide buffered register with clock enable ($\overline{\text{EN}}$) and clear ($\overline{\text{CLR}}$) ideal for parity bus interfacing in high-performance microprogrammed systems. The FCT825T is an 8-bit buffered register with all the FCT823T controls plus multiple enables ($\overline{\text{OE}}_1$, $\overline{\text{OE}}_2$, $\overline{\text{OE}}_3$) to allow multiuser control of the interface, e.g., $\overline{\text{CS}}$, DMA, and RD/WR. They are ideal for use as an output port requiring high $I_{\text{OL}}/I_{\text{OH}}$.

These devices are designed for high-capacitance load drive capability, while providing low-capacitance bus loading at both inputs and outputs. Outputs are designed for low-capacitance bus loading in the high-impedance state and are designed with a power-off disable feature to allow for live insertion of boards.



Note:

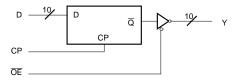
1. Not on FCT821.



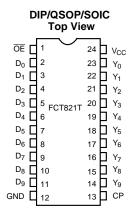


Logic Diagrams

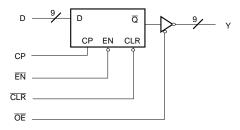
FCT821T (10-Bit Register)

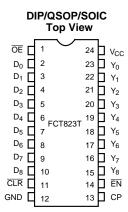


Pin Configurations

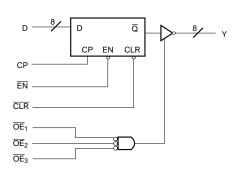


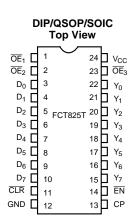
FCT823T (9-Bit Register)





FCT825T (8-Bit Register)







Pin Description

Name	I/O	Description
D	I	The D flip-flop data inputs.
CLR	I	When $\overline{\text{CLR}}$ is LOW and $\overline{\text{OE}}$ is LOW, the Q outputs are LOW. When $\overline{\text{CLR}}$ is HIGH, data can be entered into the register.
СР	0	Clock Pulse for the register; enters data into the register on the LOW-to-HIGH transition.
Υ	0	The register three-state outputs.
ĒN	I	Clock Enable. When $\overline{\text{EN}}$ is LOW, data on the D input is transferred to the Q output on the LOW-to-HIGH clock transition. When $\overline{\text{EN}}$ is HIGH, the Q outputs do not change state, regardless of the data or clock input transitions.
ŌĒ	I	Output Control. When \overline{OE} is HIGH, the Y outputs are in the high-impedance state. When \overline{OE} is LOW, the TRUE register data is present at the Y outputs.

Function Table^[2]

		Inputs			Internal	Outputs	
ŌĒ	CLR	EN	D	СР	Q	Y	Function
H H	H H	L L	L H	7	L H	Z Z	High Z
H L	L L	X X	X X	X X	L L	Z L	Clear
H L	H H	H H	X X	X X	NC NC	Z NC	Hold
H H L L	H H H	L L L	L H L	1 1 1	L H L	Z Z L H	Load

Maximum Ratings^[3,4]

(Above which the useful life may be impaired. For user guidelines, not tested.) Storage Temperature-65°C to +150°C

Ambient Temperature with Power Applied -65°C to +135°C

Supply Voltage to Ground Potential -0.5V to +7.0V DC Input Voltage -0.5V to +7.0V DC Output Voltage...... -0.5V to +7.0V

DC Output Current (Maximum Sink Current/Pin)	120 mA
Power Dissipation	0.5W
Static Discharge Voltage	>2001V
(per MIL-STD-883, Method 3015)	

Operating Range

Range	Range	Ambient Temperature	v _{cc}
Commercial	All	–40°C to +85°C	5V ± 5%

Notes:

- H = HIGH Voltage Level, L = LOW Voltage Level, X = Don't Care, NC = No Change, $\ ^{\int}$ = LOW-to-HIGH Transition, Z = HIGH Impedance. Unless otherwise noted, these limits are over the operating free-air temperature range. Unused inputs must always be connected to an appropriate logic voltage level, preferably either V_{CC} or ground.



Electrical Characteristics Over the Operating Range

Parameter	Description	Test Conditions	Min.	Typ. ^[5]	Max.	Unit
V _{OH}	Output HIGH Voltage	$V_{CC} = Min., I_{OH} = -32 \text{ mA}$	2.0			V
V _{OH}	Output HIGH Voltage	$V_{CC} = Min., I_{OH} = -15 \text{ mA}$	2.4	3.3		V
V _{OL}	Output LOW Voltage	V _{CC} = Min., I _{OL} = 64 mA		0.3	0.55	V
V _{IH}	Input HIGH Voltage		2.0			V
V _{IL}	Input LOW Voltage				0.8	V
V _H	Hysteresis ^[6]	All inputs		0.2		V
V _{IK}	Input Clamp Diode Voltage	$V_{CC} = Min., I_{IN} = -18 \text{ mA}$		-0.7	-1.2	V
I _I	Input HIGH Current	$V_{CC} = Max., V_{IN} = V_{CC}$			5	μΑ
I _{IH}	Input HIGH Current	$V_{CC} = Max., V_{IN} = 2.7V$			±1	μΑ
I _{IL}	Input LOW Current	$V_{CC} = Max., V_{IN} = 0.5V$			±1	μΑ
l _{OZH}	Off State HIGH-Level Output Current	V _{CC} = Max., V _{OUT} = 2.7V			10	μΑ
I _{OZL}	Off State LOW-Level Output Current	$V_{CC} = Max., V_{OUT} = 0.5V$			-10	μΑ
I _{OS}	Output Short Circuit Current ^[7]	V _{CC} = Max., V _{OUT} = 0.0V	-60	-120	-225	mA
I _{OFF}	Power-Off Disable	V _{CC} = 0V, V _{OUT} = 4.5V			±1	μΑ

Capacitance^[6]

Parameter	Description	Typ. ^[5]	Max.	Unit
C _{IN}	Input Capacitance	5	10	pF
C _{OUT}	Output Capacitance	9	12	pF

- Typical values are at V_{CC}=5.0V, T_A=+25°C ambient.
 This parameter is specified but not tested.
 Not more than one output should be shorted at a time. Duration of short should not exceed one second. The use of high-speed test apparatus and/or sample and hold techniques are preferable in order to minimize internal chip heating and more accurately reflect operational values. Otherwise prolonged shorting of a high output may raise the chip temperature well above normal and thereby cause invalid readings in other parametric tests. In any sequence of parameter tests, I_{OS} tests should be performed last.



Power Supply Characteristics

Parameter	Description	Test Conditions	Typ. ^[5]	Max.	Unit
I _{CC}	Quiescent Power Supply Current	V _{CC} =Max., V _{IN} ≤0.2V, V _{IN} ≥V _{CC} -0.2V	0.1	0.2	mA
ΔI_{CC}	Quiescent Power Supply Current (TTL inputs HIGH)	V _{CC} =Max., V _{IN} =3.4V, ^[8] f ₁ =0, Outputs Open	0.5	2.0	mA
I _{CCD}	Dynamic Power Supply Current ^[9]	V _{CC} =Max., One Bit Toggling, 50% Duty Cycle, Outputs Open, OE=EN=GND, V _{IN} ≤0.2V or V _{IN} ≥V _{CC} −0.2V	0.06	0.12	mA/MHz
I _C	Total Power Supply Current ^[10]	V _{CC} =Max., f ₀ =10 MHz, 50% Duty Cycle, Outputs Open, One Bit Toggling at f ₁ =5 MHz, OE=EN=GND, V _{IN} ≤0.2V or V _{IN} ≥V _{CC} −0.2V	0.7	1.4	mA
		V _{CC} =Max., f ₀ =10 MHz, 50% Duty Cycle, Outputs Open, One Bit Toggling at f ₁ =5 MHz, OE=EN=GND, V _{IN} =3.4V or V _{IN} =GND	1.2	3.4	mA
		V _{CC} =Max., f ₀ =10 MHz, 50% Duty Cycle, Outputs Open, Eight Bits Toggling at f ₁ =2.5 MHz, OE=EN=GND, V _{IN} ≤0.2V or V _{IN} ≥V _{CC} -0.2V	1.6	3.2 ^[11]	mA
		$V_{CC}=Max.$, $f_0=10$ MHz,50% Duty Cycle, Outputs Open, Eight Bits Toggling at $f_1=2.5$ MHz, $\overline{OE}=\overline{EN}=GND$, $V_{IN}=3.4V$ or $V_{IN}=GND$	3.9	12.2 ^[11]	mA

- Notes:
 8. Per TTL driven input (V_{IN}=3.4V); all other inputs at V_{CC} or GND.
 9. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.
 10. I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}
 I_C = Quiescent Current with CMOS input levels
 ΔI_{CC} = Quiescent Current with CMOS input levels
 ΔI_{CC} = Power Supply Current for a TTL HIGH input (V_{IN}=3.4V)
 D_H = Duty Cycle for TTL inputs HIGH
 N_T = Number of TTL inputs at D_H
 I_{CCD} = Dynamic Current caused by an input transition pair (HLH or LHL)
 f₀ = Clock frequency for registered devices, otherwise zero
 f₁ = Input signal frequency
 N₁ = Number of inputs changing at f₁
 All currents are in milliamps and all frequencies are in megahertz.
 11. Values for these conditions are examples of the I_{CC} formula. These limits are specified but not tested.



Switching Characteristics Over the Operating Range^[12]

			CY74FCT CY74FCT	Γ823AT	CY74FC CY74FC CY74FC	T823BT	CY74FCT CY74FCT	Г823CT		
			Commo	ercial	Comm	ercial	Comm	ercial		
Param.	Description	Test Load	Min.	Max.	Min.	Max.	Min.	Max.	Unit	Fig. No. ^[13]
t _{PLH} t _{PHL}	Propagation Delay CP to Y, (OE=LOW)	$C_L=50 \text{ pF}$ $R_L=500\Omega$		10.0		7.5		6.0	ns	1, 5
t _{PLH} t _{PHL}	Propagation Delay CP to Y, (OE=LOW) ^[6]	C_L =300 pF R_L =500 Ω		20.0		15.0		12.5	ns	1, 5
t _{PLH}	Propagation Delay CLR to Y	$C_L=50 \text{ pF}$ $R_L=500\Omega$		14.0		9.0		8.0	ns	1, 5
t _{PZH}	Output Enable Time OE to Y	C_L =50 pF R_L =500 Ω		12.0		8.0		7.0	ns	1, 7, 8
t _{PZH}	Output Enable Time OE to Y ^[6]	$C_L = 300 \text{ pF} \\ R_L = 500 \Omega$		23.0		15.0		12.5	ns	1, 7, 8
t _{PHZ}	Output Disable Time OE to Y ^[6]	$C_L=5 \text{ pF}$ $R_L=500\Omega$		7.0		6.5		6.0	ns	1, 7, 8
t _{PHZ}	Output Disable Time OE to Y	C_L =50 pF R_L =500 Ω		8.0		7.5		6.5	ns	1, 7, 8
t _{SU}	Data to CP, Set-Up Time		4.0		3.0		3.0		ns	4
t _H	Data to CP, Hold Time		2.0		1.5		1.5		ns	4
t _{SU}	Enable EN to CP, Set-Up Time		4.0		3.0		3.0		ns	4
t _H	Enable EN to CP, Hold Time	C _L =50 pF R _I =500Ω	2.0		0.0		0.0		ns	4
t _{REM}	Clear Recovery Time, CLR to CP	1.1_00032	6.0		6.0		6.0		ns	6
t _W	Clock Pulse Width		7.0		6.0		6.0		ns	5
t _W	CLR Pulse Width LOW		6.0		6.0		6.0		ns	5

Notes:

^{12.} Minimum limits are specified but not tested on Propagation Delays.13. See "Parameter Measurement Information."



Ordering Information—FCT821T

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
6.0	CY74FCT821CTQCT	Q13	24-Lead (150-Mil) QSOP	Commercial
	CY74FCT821CTSOC/SOCT	S13	24-Lead (300-Mil) Molded SOIC	
7.5	CY74FCT821BTPC	P13/13A	24-Lead (300-Mil) Molded DIP	Commercial
	CY74FCT821BTSOC/SOCT	S13	24-Lead (300-Mil) Molded SOIC	
10.0	CY74FCT821ATQCT	Q13	24-Lead (150-Mil) QSOP	Commercial
	CY74FCT821ATSOC/SOCT	S13	24-Lead (300-Mil) Molded SOIC	

Ordering Information—FCT823T

Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
6.0	CY74FCT823CTQCT	Q13	24-Lead (150-Mil) QSOP	Commercial
	CY74FCT823CTSOC/SOCT	S13	24-Lead (300-Mil) Molded SOIC	
7.5	CY74FCT823BTPC	P13/13A	24-Lead (300-Mil) Molded DIP	Commercial
10.0	CY74FCT823ATPC	P13/13A	24-Lead (300-Mil) Molded DIP	Commercial
	CY74FCT823ATQCT	Q13	24-Lead (150-Mil) QSOP	
	CY74FCT823ATSOC/SOCT	S13	24-Lead (300-Mil) Molded SOIC	

Ordering Information—FCT825T

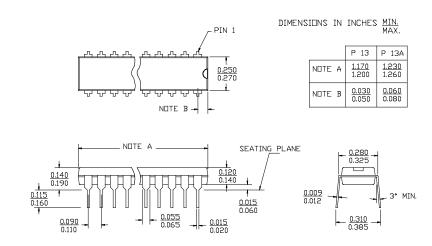
Speed (ns)	Ordering Code	Package Name	Package Type	Operating Range
6.0	CY74FCT825CTQCT	Q13	24-Lead (150-Mil) QSOP	Commercial

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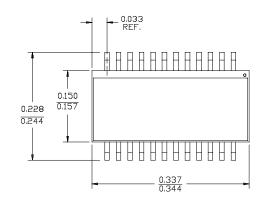


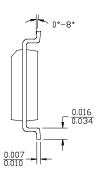
Package Diagrams

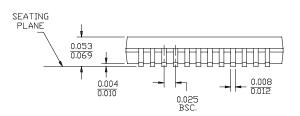
24-Lead (300-Mil) Molded DIP P13/P13A



24-Lead Quarter Size Outline Q13





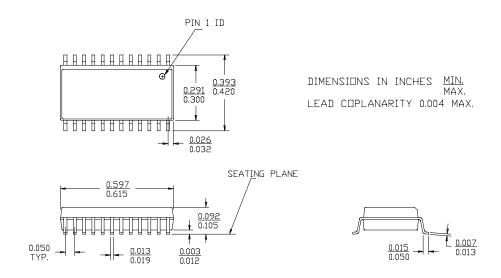


DIMENSIONS IN INCHES $\frac{\text{MIN.}}{\text{MAX.}}$ LEAD COPLANARITY 0.004 MAX.



Package Diagrams (continued)

24-Lead (300-Mil) Molded SOIC S13



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